

LECTURE -9

FERMI - LEVELS IN SEMICONDUCTORS

* ELECTRONS BEHAVE USING FERMI-DIRAC STATISTICS

DISTRIBUTION OF ELECTRONS OVER A RANGE OF ALLOWED ENERGY LEVELS AT THERMAL EQUILIBRIUM

$$f(E) = \frac{1}{1 + e^{(E-E_F)/KT}}$$

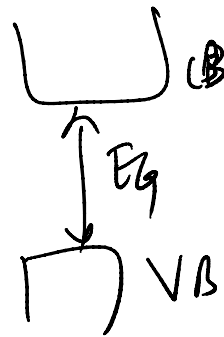
→ FERMI-DIRAC DISTRIBUTION FUNCTION!

$f(E)$ GIVES THE PROBABILITY THAT AN AVAILABLE ENERGY STATE AT "E" WILL BE OCCUPIED BY AN ELECTRON AT TEMP. T

AT $E = E_F$ $f(E) = \frac{1}{1 + e^{(E_F - E_F)/KT}} = \frac{1}{2}$
 \Rightarrow 50%.

* NO ELECTRON CAN EXIST IN BAND GAP EVEN THOUGH A FINITE PROBABILITY EXISTS!

\therefore
NO STATES ARE AVAILABLE IN E_g !



Thursday, January 10, 2013
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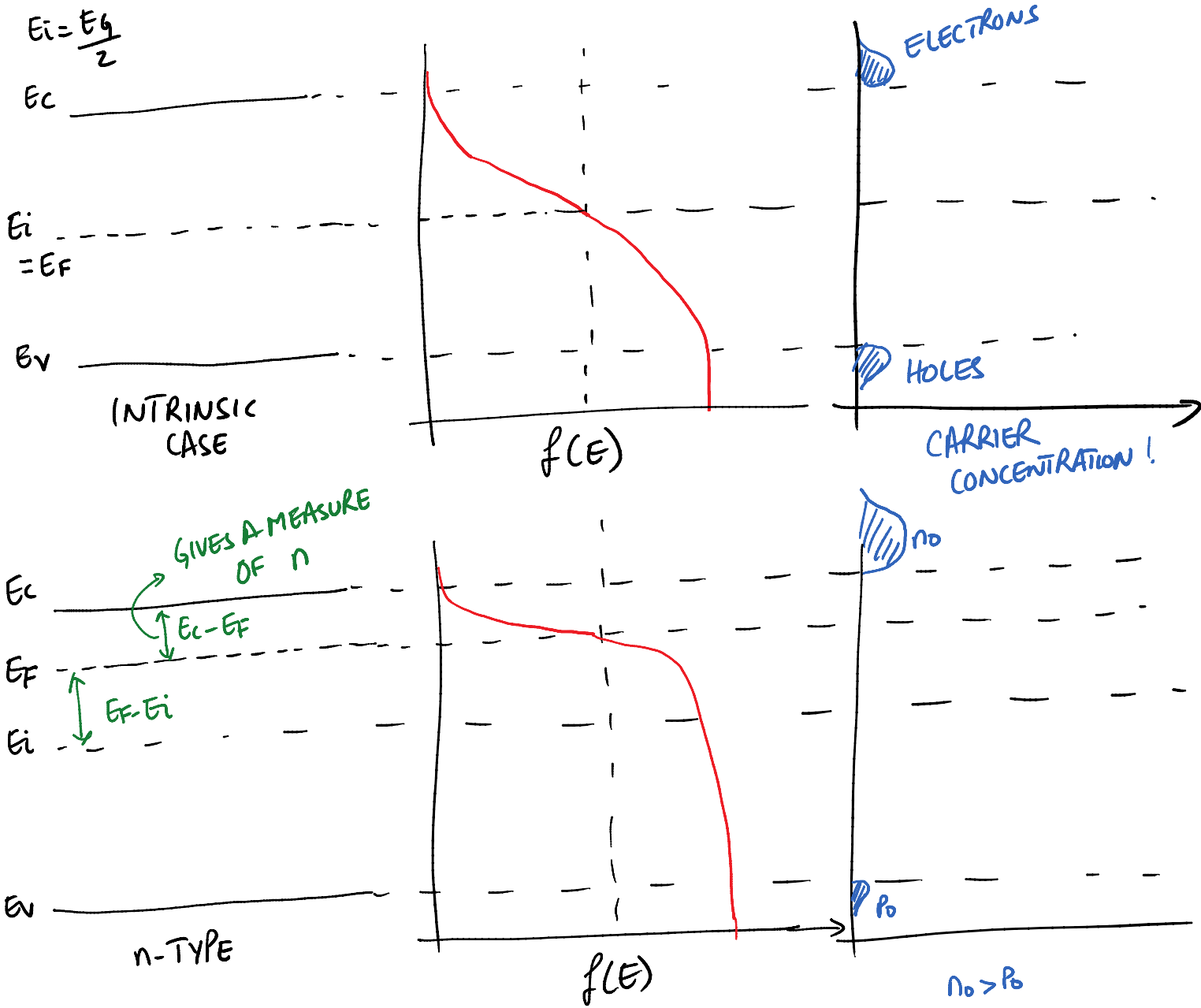
$$n_0 = n_i e^{\frac{(E_F - E_i)}{KT}}$$

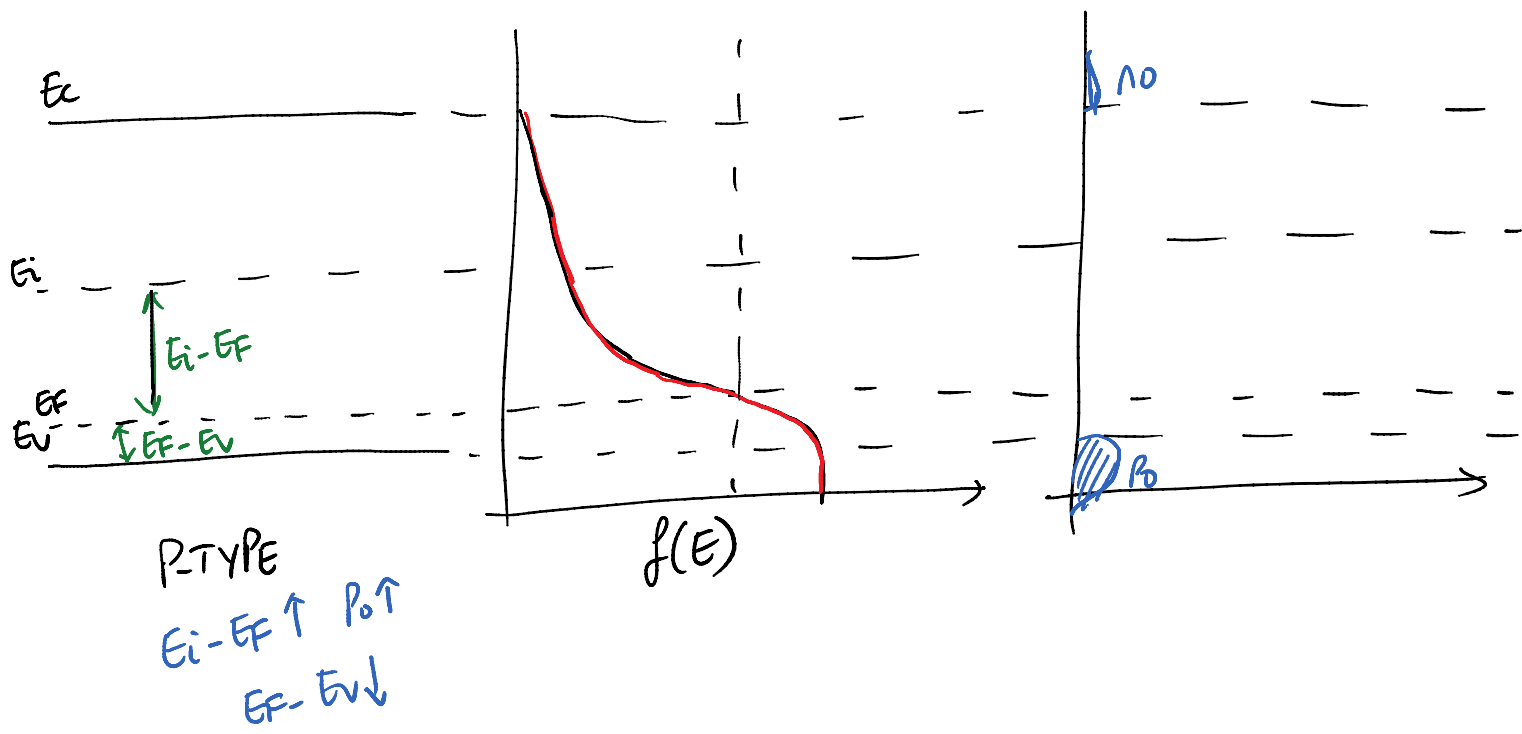
$E_F - E_i \uparrow$
 $E_c - E_F \downarrow$ $n_0 \uparrow$

$$E_F - E_i = KT \ln \left(\frac{n_0}{n_i} \right)$$

$$p_0 = n_i e^{\frac{(E_i - E_F)}{KT}}$$

$$E_i - E_F = KT \ln \left(\frac{p_0}{n_i} \right)$$





* $\frac{E_x}{RT}$ CAN USE APPROX. FOR n_0 AND p_0
↳ DEPENDS ON THE PROBLEM!

$\frac{Si}{RT}$

$$E_g = 1.12 \text{ eV}$$

$$kT = 0.0259 \text{ eV}$$

$$N_a^- = 1 \times 10^{12} \text{ cm}^{-3} \rightarrow \text{P-TYPE MATERIAL}$$

p_0 MAJORITY!

FOR SMALL PROBLEM APPROX.

$$p_0 = 1 \times 10^{12} \text{ cm}^{-3}$$

$$n_0 = 2.25 \times 10^8 \text{ cm}^{-3}$$

$$n_0 p_0 = n_i^2$$

$$E_i - E_F = kT \ln \left(\frac{p_0}{n_i} \right)$$

$$= 0.0259 \ln \left(\frac{1 \times 10^{12}}{1.5 \times 10^{10}} \right)$$

$$E_i - E_F = 0.1087 \text{ eV}$$

$$E_F - E_i = -0.1087 \text{ eV}$$

$$E_i > E_F$$

